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(54) Metal coordination compound, luminescence device and display apparatus

Metallkomplex, lumineszierende Anordnung und Anzeigevorrichtung

Complexes métalliques, dispositif luminescent, et dispositif d'affichage

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Description

FIELD OF THE INVENTION AND RELATED ART

- ⁵ **[0001]** The present invention relates to a luminescence device, a display apparatus and a metal coordination compound therefor. More specifically, the present invention relates to a luminescence device employing an organic metal coordination compound having a formula (1) appearing hereinafter as a luminescence material so as to allow stable luminescence efficiency, a display apparatus including the luminescence device and the metal coordination compound adapted for use in the luminescence device.
- ¹⁰ **[0002]** An organic electroluminescence (EL) device has been extensively studied as a luminescence device with a high responsiveness and high efficiency.

[0003] The organic EL device generally has a sectional structure as shown in Figure 1A or 1B (e.g., as described in "Macromol. Symp.", 125, pp. 1 - 48 (1997)).

- [0004] Referring to the figures, the EL device generally has a structure including a transparent substrate 15, a transparent electrode 14 disposed on the transparent substrate 15, a metal electrode 11 disposed opposite to the transparent electrode 14 disposed on the transparent substrate 15, a metal electrode 11 disposed opposite to the transparent
- electrode 14, and a plurality of organic (compound) layers disposed between the transparent electrode 14 and the metal electrode 11.

[0005] Referring to Figure 1, the EL device in this embodiment has two organic layers including a luminescence layer 12 and a hole transport layer 13.

- 20 **[0006]** The transparent electrode 14 may be formed of a film of ITO (indium tin oxide) having a larger work function to ensure a good hole injection performance into the hole transport layer. On the other hand, the metal electrode 11 may be formed of a layer of aluminum, magnesium, alloys thereof, etc., having a smaller work function to ensure a good electron injection performance into the organic layer(s).
 - [0007] These (transparent and metal) electrodes 14 and 11 may be formed in a thickness of 50 200 nm.
- 25 [0008] The luminescence layer 12 may be formed of, e.g., aluminum quinolinol complex (representative example thereof may include Alq3 described hereinafter) having an electron transporting characteristic and a luminescent characteristic. The hole transport layer 13 may be formed of, e.g., triphenyldiamine derivative (representative example thereof may include α-NPD described hereinafter) having an electron donating characteristic.
- [0009] The above-described EL device exhibits a rectification characteristic, so that when an electric field is applied
 ³⁰ between the metal electrode 11 as a cathode and the transparent electrode 14 as an anode, electrons are injected from the metal electrode 11 into the luminescence layer 12 and holes are injected from the transparent electrodes 14.
 [0010] The thus-injected holes and electrons are recombined within the luminescence layer 12 to produce excitons, thus causing luminescence. At that time, the hole transport layer 13 functions as an electron-blocking layer to increase
- a recombination efficiency at the boundary between the luminescence layer 12 and the hole transport layer 13, thus enhancing a luminescence efficiency.

[0011] Referring to Figure 1B, in addition to the layers shown in Figure 1A, an electron transport layer 16 is disposed between the metal electrode 11 and the luminescence layer 12, whereby an effective carrier blocking performance can be ensured by separating functions of luminescence, electron transport and hole transport, thus allowing effective luminescence.

40 **[0012]** The electron transport layer 16 may be formed of, e.g., oxadiazole derivatives.

[0013] In ordinary organic EL devices, fluorescence caused during a transition of luminescent center molecule from a singlet excited state to a ground state is used as luminescence.

[0014] On the other hand, not the above fluorescence (luminescence) via singlet exciton, phosphorescence (luminescence) via triplet exciton has been studied for use in organic EL device as described in, e.g., "Improved energy transfer

⁴⁵ in electrophosphorescent device" (D.F. O'Brien et al., Applied Physics Letters, Vol. 74, No. 3, pp. 442 - 444 (1999)) and "Very high-efficiency green organic light-emitting devices based on electrophosphorescence" (M.A. Baldo et al., Applied Physics Letters, Vol. 75, No. 1, pp. 4 - 6 (1999)).

[0015] The EL devices shown in these documents may generally have a sectional structure shown in Figure 1C.

[0016] Referring to Figure 1C, four organic layers including a hole transfer layer 13, a luminescence layer 12, an exciton diffusion-prevention layer 17, and an electron transport layer 16 are successively formed in this order on the transparent electrode (anode) 14.

[0017] In the above documents, higher efficiencies have been achieved by using four organic layers including a hole transport layer 13 of α -NPD (shown below), an electron transport layer 16 of Alq3 (shown below), an exciton diffusion-prevention layer 17 of BPC (shown below), and a luminescence layer 12 of a mixture of CPB (shown below) as a host

⁵⁵ material with Ir(ppy)₃ (shown below) or PtOEP (shown below) as a guest phosphorescence material doped into CBP at a concentration of ca. 6 wt. %.



 α -NPD

Alq3



40 Ir.

lr(ppy)₃

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Alq3: tris(8-hydroxyquinoline) aluminum (aluminum-quinolinol complex),
α-NPD: N4,N4'-di-naphthalene-1-yl-N4,N4'-diphenyl-biphenyl-4,4'-diamine (4,4'-bis[N-(1-naphthyl)-N-phenyl-amino]biphenyl),
CBP: 4,4'-N,N'-dicarbazole-biphenyl,
BCP: 2,9-dimethyl-4,7-diphenyl-1,10-phenanthroline,

Ir(ppy)3: fac tris(2-phenylpyridine)iridium (iridium-phenylpyridine complex), and

PtEOP: 2,3,7,8,12,13,17,18-octaethyl-21H,23H-porphine platinum (platinum-octaethyl porphine complex).

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[0018] The phosphorescence (luminescence) material used in the luminescence layer 12 has attracted notice. This is because the phosphorescence material is expected to provide a higher luminescence efficiency in principle.

[0019] More specifically, in the case of the phosphorescence material, excitons produced by recombination of carriers comprise singlet excitons and triplet excitons presented in a ratio of 1:3. For this reason, when fluorescence caused during the transition from the singlet excited state to the ground state is utilized, a resultant luminocence officiency is

- ⁵ during the transition from the singlet excited state to the ground state is utilized, a resultant luminescence efficiency is 25 % (as upper limit) based on all the produced excitons in principle.
 [0020] On the other hand, in the case of utilizing phosphorescence caused during transition from the triplet excited to be at least these times that of the case of fluencescence is
 - state, a resultant luminescence efficiency is expected to be at least three times that of the case of fluorescence in principle. In addition thereto, if intersystem crossing from the singlet excited state (higher energy level) to the triplet excited state is taken into consideration, the luminescence efficiency of phosphorescence can be expected to be 100 % (four times that of fluorescence) in principle.

[0021] The use of phosphorescence based on transition from the triplet excited state has also been proposed in, e.g., Japanese Laid-Open Patent Application (JP-A) 11-329739, JP-A 11-256148 and JP-A 8-319482.

- [0022] However, the above-mentioned organic EL devices utilizing phosphorescence have accompanied with a problem of luminescent deterioration particularly in an energized state.
 - **[0023]** The reason for luminescent deterioration has not been clarified as yet but may be attributable to such a phenomenon that the life of triplet exciton is generally longer than that of singlet exciton by at least three digits, so that molecule is placed in a higher-energy state for a long period to cause reaction with ambient substance, formation of exciplex or excimer, change in minute molecular structure, structural change of ambient substance, etc.
- 20 [0024] Accordingly, the (electro)phosphorescence EL device is expected to provide a higher luminescence efficiency as described above, while the EL device is required to suppress or minimize the luminescent deterioration in energized state. Further, a luminescence center material for the EL device is required to allow high-efficiency luminescence and exhibit a good stability.
- **[0025]** WO 00/70655 refers to organic light emitting devices in which the emissive layer comprises a host material containing an emissive molecule, which molecule is adapted to luminesce when a voltage is applied across the heter-ostructure, and the emissive molecule is selected from the group of phosphorescent organometallic compounds, including cyclometallated iridium compounds and wherein the devices contain an exciton blocking layer.

SUMMARY OF THE INVENTION

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[0026] An object of the present invention is to provide a luminescence device capable of providing a high-efficiency luminescent state at a high brightness (or luminance) for a long period while minimizing the deterioration in luminescence in energized state.

- [0027] Another object of the present invention is to provide a display apparatus including the luminescence device.
- ³⁵ **[0028]** A further object of the present invention is to provide a metal coordination compound as a luminescence center material suitable for an organic layer for the luminescence device.
 - [0029] According to the present invention, there is provided a metal coordination compound as defined in claim 1.
 - **[0030]** The present invention also provides an electroluminescence device as defined in claim 2.
 - [0031] In the electroluminescence device, a voltage is applied between the electrodes to emit light.
- ⁴⁰ **[0032]** In a preferred embodiment of the electroluminescence device, a voltage is applied between the electrodes to emit phosphorescence.

[0033] The present invention further provides a picture display apparatus, comprising an electroluminescence device described above and a means for supplying electric signals to the electroluminescence device.

[0034] These and other objects, features and advantages of the present invention will become more apparent upon a consideration of the following description of the preferred embodiments of the present invention taken in conjunction with the accompanying drawings.

BRIEF DESCRIPTION OF THE DRAWINGS

50 **[0035]**

Figures 1A, 1B and 1C illustrate embodiments of the luminescence device according to the present invention, respectively.

Figure 2 schematically illustrates a panel structure including an EL device and drive means.

⁵⁵ Figures 3A, 3B and 3C show device performances of a luminescence device used in Example 9 appearing hereinafter, wherein Figure 3A shows an electric field strength-current density curve, Figure 3B shows an electric field strength-luminance curve, and Figure 3C shows a luminescence spectrum under application of a voltage of 10 volts.

DETAILED DESCRIPTION OF THE INVENTION

[0036] In the case where the luminescence layer comprises a host material having a carrier-transporting function and a phosphorescent guest material, a process of phosphorescence via triplet excitons may include unit processes as follows:

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- 1. transportation of electrons and holes within a luminescence layer,
- 2. formation of host excitons,
- 3. excitation energy transfer between host molecules,
- 4. excitation energy transfer from the host to the guest,
- 10 5. formation of guest triplet excitons, and
 - 6. transition of the guest triplet excitons to the ground state and phosphorescence.

[0037] Desirable energy transfer in each unit process and luminescence are caused in competition with various energy deactivation processes.

- 15 [0038] Needless to say, a luminescence efficiency of an organic luminescence device is increased by increasing the luminescence quantum yield of a luminescence center material. In addition thereto, an efficient energy transfer between host material molecules and/or between host material molecule and guest material molecule is also an important factor. [0039] Further, the above-described luminescent deterioration in energized state may presumably relate to the luminescent center material per se or an environmental change thereof by its ambient molecular structure.
- 20 [0040] For this reason, our research group has extensively investigated an effect of use of the metal coordination compound as defined in claim 1 as the luminescent center material and as a result, has found that this metal coordination compound allows a high-efficiency luminescence with a high brightness (luminance) for a long period, and less deterioration in energized state.
- **[0041]** The metal coordination compound according to the present invention causes phosphorescence (luminescence) and its lowest excited state is believed to be an MLT^{*} (metal-to-ligand charge transfer) excited state or $n-\pi^*$ excited state in a triplet state. The phosphorescent emission of light (phosphorescence) is caused at the time of transition from such a state to the ground state.

[0042] The metal coordination compound according to the present invention has been found to provide a higher phosphorescence (quantum) yield of 0.05 - 0.9 and a shorter phosphorescence life of 1 - 40 µsec, as a result of our luminescence experiment based on photoluminescence by photo-excitation.

- **[0043]** The shorter phosphorescence life is necessary to provide a resultant EL device with a higher luminescence efficiency. This is because the longer phosphorescence life increases molecules placed in their triplet excited state which is a waiting state for phosphorescence, thus lowering the resultant luminescence efficiency particularly at a higher current density. Further, an emission wavelength can be controlled
- ³⁵ **[0044]** Also from these viewpoints, the metal coordination compound according to the present invention is a suitable luminescent material for an EL device with a higher phosphorescence yield and a shorter phosphorescence life. **[0045]** Particularly, by providing an aromatic group as a substituent (i.e., aromatic substituent) of the metal coordination compound, the resultant substituent has π -electron system extended to the outside of the metal coordination compound molecules, thus facilitating energy transfer from a host material and assisting electron/hole transport functions to result
- in an improved carrier transport performance. The resultant metal coordination compound can be synthesized with a high yield and an excellent stability necessary for the luminescence material.
 [0046] In addition, as substantiated in Examples appearing hereinafter, it has been confirmed that the metal coordination compound also exhibited an excellent stability in a durability test by continuous current passage. This may be attributable to a controlled intermolecular interaction of the metal coordination compound with the host material by having
- 45 the aromatic substituent characterizing the metal coordination compound of the present invention thereby to change an intermolecular interaction. As a result, it becomes possible to suppress formation of exciton associates leading to thermal deactivation, thus also reducing quenching process to improve phosphorescence yield and device characteristics. [0047] In the present invention, as the aromatic substituent for the metal coordination compound of the formula (I), selected from the group consisting of those (sPh to those shown in formula (1) to (17) in claim 1 are used.
- ⁵⁰ **[0048]** In the present invention, the luminescence device may preferably include the organic layer comprising the above-mentioned metal coordination compound between a pair of oppositely disposed electrodes comprising a transparent electrode (anode) and a metal electrode (cathode) which are supplied with a voltage to cause luminescence, thus constituting an electric-field luminescence device.

[0049] The luminescence device of the present invention has a layer structure shown in Figures 1A to 1C as specifically described above.

[0050] By the use of the metal coordination compound of the present invention, the resultant luminescence device has a high luminescence efficiency as described above.

[0051] The luminescence device according to the present invention may be applicable to devices required to allow

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energy saving and high luminance, such as those for display apparatus and illumination apparatus, a light source for printers, and backlight (unit) for a liquid crystal display apparatus. Specifically, in the case of using the luminescence device of the present invention in the display apparatus, it is possible to provide a flat panel display apparatus capable of exhibiting an excellent energy saving performance, a high visibility and a good lightweight property. With respect to

- 5 the light source, it becomes possible to replace a laser light source of laser beam printer currently used widely with the luminescence device according to the present invention. Further, when the luminescence device of the present invention is arranged in independently addressable arrays as an exposure means for effecting desired exposure of light to a photosensitive drum for forming an image, it becomes possible to considerably reducing the volume (size) of image forming apparatus. With respect to the illumination apparatus and backlight (unit), the resultant apparatus (unit) using
- 10 the luminescence device of the present invention is expected to have an energy saving effect. [0052] For the application to a display, a drive system using a thin-film transistor (TFT) drive circuit according to an active matrix-scheme may be used. Hereinbelow, an embodiment of using a device of the present invention in combination with an active matrix substrate is briefly described with reference to Figure 2.
- [0053] Figure 2 illustrates an embodiment of panel structure comprising an EL device and drive means. The panel is provided with a scanning signal driver, a data signal driver and a current supply source which are connected to gate selection lines, data signal lines and current supply lines, respectively. At each intersection of the gate selection lines and the data signal lines, a display pixel electrode is disposed. The scanning signal drive sequentially selects the gate selection lines G1, G2, G3 ... Gn, and in synchronism herewith, picture signals are supplied from the data signal driver to display a picture (image).
- 20 **[0054]** By driving a display panel including a luminescence layer comprising a luminescence material of the present invention, it becomes possible to provide a display which exhibits a good picture quality and is stable even for a long period display.

[0055] Some synthetic paths for providing the metal coordination compound are illustrated below with reference to an iridium coordination compound (m+n = 3):



formula (1):

45 50 formula (10):



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formula (2):



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formula (3):





formula (4):



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formula (5):







formula (12):



formula (13):



formula (14):



formula (6): formula (15): 5 10 3. 3. 15 formula (7): formula (16): 20 3 25 2. formula (8): formula (17): 30 Hg ₄H₀ tr 35 2. 3. DCH 40 formula (9): 45 h 3 50

[0057] Hereinbelow, the present invention will be described more specifically based on Examples. <u>Examples</u> 1, 2, 4, and 6

⁵⁵ **[0058]** Each of luminescence devices having a layer structure shown in Figure 1B were prepared in the following manner.

[0059] On a 1.1 mm-thick glass substrate (transparent substrate 15), a 100 nm-thick film (transparent electrode 14) of ITO (indium tin oxide) was formed by sputtering, followed by patterning to form a stripe electrode including 100 lines

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each having a width of 100 nm and a spacing with an adjacent line of 10 nm (i.e., electrode pitch of 110 nm). [0060] On the ITO-formed substrate, three organic layers and two metal electrode layers shown below were successively formed by vacuum (vapor) deposition using resistance heating in a vacuum chamber (10⁻⁴ Pa).

- Organic layer 1 (hole transport layer 13) (40 nm): α-NPD
 Organic layer 2 (luminescence layer 12) (30 nm): co-deposited film of CBP:metal complex (metal coordination compound shown in Table 18) (95:5 by weight)
 Organic layer 3 (electron transport layer 16) (30 nm): Alq3
 Metal electrode layer 1 (metal electrode 11) (15 nm): Al-Li alloy (Li = 1.8 wt. %)
- 10 Metal electrode layer 2 (metal electrode 11) (100 nm): Al

[0061] The above-deposited metal electrode layers 1 and 2 (Al-Li layer and Al layer) had a stripe electrode pattern including 100 lines each having a width of 100 nm and a spacing of 10 nm (electrode pitch = 110 nm) and arranged so that the stripe electrode pattern intersected with that of the ITO electrode at right angles to form a matrix of pixels each

¹⁵ having an effective electrode area of 3 mm² comprising 20 ITO lines bundled together at a lead-out portion and 15 Al (Al-Li) lines bundled together at a lead-out portion.

[0062] Each of the thus-prepared luminescence devices was taken out of the vacuum chamber and was subjected to a continuous energization (current passage) test in an atmosphere of dry nitrogen gas stream so as to remove device deterioration factors, such as oxygen and moisture (water content).

- 20 [0063] The continuous energization test was performed by continuously applying a voltage at a constant current density of 50 mA/cm² to the luminescence device having the ITO (transparent) electrode (as an anode) and the AI (metal) electrode (as a cathode), followed by measurement of emission luminance (brightness) with time so as to determine a time (luminance half-life) required for decreasing an initial luminance (60 220 cd/m²) to 1/2 thereof.
 - **[0064]** The results are shown in Table 18 appearing hereinafter.
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Comparative Example 1

[0065] A comparative luminescence device was prepared and evaluated in the same manner as in the above Examples except that the Ir complexes (metal coordination compounds shown in Table 18) was changed to Ir-phenylpyrimidine complex (Ir(ppy)₃) shown below.

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[0066]	The results are also shown in Table 18 below.	

	Table 18		
Ex. No.	Compound (Formula No.)	Luminance half-life (Hr)	
Ex. 1	(1)	450	
Ex. 2	(9) Ex 9	550	
Ex. 4	(43)	500	
Ex. 6	(385)	400	
Comp.Ex. 1	lr(ppy) ₃	300	

[0067] As is apparent from Table 18, compared with the conventional luminescence device using lr(ppy)₃, the luminescence devices using the metal coordination compounds of formula (1) according to the present invention provide longer luminance half-lives, thus resulting in an EL device having a high durability (luminance stability) based on a good stability of the metal coordination compound of formula (1) of the present invention.



Example 9 (Synthesis of Ex. Comp. No. 11)

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[0068] A metal coordination compound (Ex. Comp. No. 11) was synthesized through the following reaction schemes. Hereinafter, the synthesis yield is simply represented by "Y".





[0069] According to MALDI-TOF MS, the compound exhibited M^+ = 919.0, thus being identified as the objective iridium compound.

- 30 [0070] When the compound was dissolved in toluene and subjected to measurement of phosphorescence spectrum at an excited light wavelength of 400 nm by using a fluorescence spectrometer, the compound exhibited a phosphorescence spectrum showing λmax (maximum emission wavelength) of 612 nm, thus confirming clear red luminescence.
 [0071] When a luminescence device having a layer structure shown below and using the above-synthesized metal
- coordination compound (Ex. Comp. No. 11) was prepared and subjected to measurement of phosphorescence spectrum
 in a similar manner, a clear red luminescence was confirmed similarly as in the case of the compound in toluene described above.

[0072] ITO (100 nm)/α-NPD (40 nm)/CBP: Ex. Comp. No. 11 (95:5 by weight)(30 nm)/BCP (20 nm)/Alq3 (40 nm)/Al-Li (1 nm)/Al (100 nm).

[0073] Further, the luminescence device exhibited a good rectifying characteristic.

- 40 [0074] Specifically, Figure 3A is a graph showing a relationship between an electric field strength (E) and a current density of the luminescence device, and Figure 3B is a graph showing a relationship between an electric field strength (E) and a luminance (L) of the luminescence device. Further, Figure 3C shows a luminescence spectrum of the luminescence device under application of a voltage of 10 volts.
- [0075] The luminescence device exhibited a luminescence efficiency of 0.8 lm/W under application of a voltage of 10 volts. The luminescence device also emitted stable luminescence even when the luminescence device was continuously supplied with the voltage for ca. 200 hours.

Example 10 (Synthesis of Ex. Comp. No. 45)

⁵⁰ **[0076]** A metal coordination compound (Ex. Comp. No. 45) was synthesized through the following reaction schemes.



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[0077] According to MALDI-TOF MS, the compound exhibited M^+ = 1183.3, thus being identified as the objective iridium compound.

[0078] When the compound was dissolved in toluene and subjected to measurement of phosphorescence spectrum at an excited light wavelength of 380 nm by using a fluorescence spectrometer, the compound exhibited a phosphorescence spectrum showing λ max (maximum emission wavelength) of 603 nm, thus confirming clear reddish orange luminescence.

[0079] When the luminescence device prepared in Example 5 using the above-synthesized metal coordination compound (Ex. Comp. No. 45) was subjected to measurement of phosphorescence spectrum in a similar manner, a clear reddish orange luminescence was confirmed similarly as in the case of the compound in toluene described above.

³⁵ **[0080]** Further, the luminescence device exhibited a good rectifying characteristic.

[0081] The luminescence device exhibited a luminescence efficiency of 0.5 lm/W under application of a voltage of 8 volts. The luminescence device also emitted stable luminescence even when the luminescence device was continuously supplied with the voltage for ca. 150 hours.

40 Example 12 (Another synthesis of Ex. Comp. No. 45)

[0082] The metal coordination compound (Ex. Comp. No. 45) prepared in Example 10 was synthesized through another reaction schemes shown below.

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[0083] In a 200 ml-three-necked flask, 0.58 mg (1.64 mmole) of iridium (III) chloride-trihydrate (made by Across 20 Organics Co.), 1.7 g (5.1 mmole) of a compound (1), 45 ml of ethoxyethanol and 15 ml of water were placed and stirred for 30 min. at room temperature under nitrogen stream, followed by 24 hours of reflux under stirring. The reaction product was cooled to room temperature, and the precipitate was recovered by filtration and washed with water, followed successive washing with ethanol and acetone. After drying under a reduced pressure at room temperature, 1.0 g (yield = 93.4 %) of red powdery compound (2) was obtained. 25



[0084] In a 200 ml-three-necked flask, 70 ml of ethoxyethanol, 0.90 g (0.71 mmole) of the compound (2), 0.22 g (2.10 mmole) of acetylacetone and 1.04 g (9.91 mmole) of sodium carbonate, were placed and stirred for 1 hour at room temperature under nitrogen stream and then refluxed under stirring for 15 hours. The reaction product was cooled with 45 ice, and the precipitate was filtered out and washed with water. The precipitate was then purified by silica gel column chromatography (eluent: chloroform/methanol = 30/1) to obtain 0.39 g of red powdery compound (3) (Example Compound No. 519). According to MALDI-TOF MS, M⁺ of 952.3 of the compound was confirmed. A toluene solution of the compound exhibited a luminescence spectrum showing λmax = 608 nm and a higher quantum yield of 0.30 relative to 1.0 of Ir $(ppy)_3$ in this emission wavelength region.

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- 20 [0085] In a 100 ml-three-necked flask, 0.29 g (0.88 mM) of the compound (1) 0.34 g (0.35 mM) of the compound (3) and 25 ml of glycerol, were placed and heated around 180 °C for 8 hours under stirring and nitrogen stream. The reaction product was cooled to room temperature and poured into 170 ml of 1N-hydrochloric acid, and the precipitate was filtered out, washed with water and dried at 100 °C under a reduced pressure for 5 hours. The precipitate was purified by silica gel column chromatography with chloroform as the eluent to obtain 0.23 g of red powdery compound (4) (Example
- ²⁵ Compound No. 45). According to MALDI-TOF MS, M⁺ of 1183.4 of the compound was confirmed. A toluene solution of the compound exhibited a luminescence spectrum showing λ max = 603 nm and a quantum yield of 0.278 relative to 1.0 of Ir(ppy)₃.

[0086] The above-synthesized compound and a luminescence device prepared by using the compound exhibited luminescence characteristics similar to those of the compound and luminescence device prepared in Example 10.

- 30 [0087] The compound (3) (Ex. Comp. No. 519) prepared in this example as an intermediate product exhibited λmax which was longer by ca. 4 nm than that of the final product (Ex. Comp. No. 45) having three identical ligands. Further, when a luminescence device using the intermediate product was prepared and evaluated in the same manner as in Example 10, the luminescence device exhibited a luminescence spectrum showing λmax = 608 nm and an external luminescence yield of 0.7 lm/W. Further, the luminescence device emitted stable luminescence even when continuously
- ³⁵ supplied with the voltage for ca. 100 hours. Accordingly, the intermediate product used in this example can also be used as a luminescence material.

Example 13 (Synthesis of Ex. Comp. Nos. 520 and 525)

- 40 [0088] It is easy to synthesize the following compounds in the same manner as in Example 11 except that 4-chloropyrimidine is synthesized from 4(3H)-pyrimidone (made by Aldrich Co.) in the same manner as the process described at pages 37 and 38 of JP-A (Tokuhyo) 2001-504113 (corr. to U.S. Patent No. 6,300,330) and is reacted with 4-phenylboronic acid (made by Lancaster Co.) to obtain 4-(biphenyl-4-yl)pyrimidine, which is used instead of 2-(benzo[b]thienyl)-5-phenylpyridine.
- ⁴⁵ **[0089]** Bis[4-(biphenyl-4-yl)pyrimidine-C³,N³] (acetylacetonato) iridium (III) (Ex. Comp. No. 520).
 - **[0090]** Tris[4-(biphenyl-4-yl)pyrimidine-C³,N³] iridium (III) (Ex. Comp. No. 525).

Example 14 (Synthesis of Ex. Comp. Nos. 521 and 526)

- ⁵⁰ **[0091]** It is easy to synthesize the following compounds in the same manner as in Example 11 except that 4-(4-chlorophenyl)pyrimidine is synthesized from 4-chloropyrimidine prepared in Example 13 and 4-chlorophenylboronic acid (made by Aldrich Co.) and was reacted with 2-naphthaleneboronic acid (made by Lancaster Co.) to obtain 4-[4-(2-naphthyl)phenyl]-pyrimidine, which is used instead of 2-(benzo[b]thienyl)-5-phenylpyridine.
- **[0092]** Bis{4-[4-(2-naphthyl)phenyl]pyrimidine-C²,N³}(acetylacetonato)iridium (III) (Ex. Comp. No. 521).
- ⁵⁵ [0093] Tris{4-[4-(2-naphthyl)phenyl]pyrimidine-C²N³}iridium (III) (Ex. Comp. No. 526).

Example 15 (Synthesis of Ex. Comp. Nos. 522 and 527)

[0094] It is easy to synthesize the following compounds in the same manner as in Example 11 except that 2,4diphenylpyridine is synthesized from phenylboronic acid (made by Tokyo Kasei Kogyo K.K.) and 4-phenyl-2-bromopyridine (made by General Intermediates of Canada) and was used instead of 2-(benzo[b]thienyl)-5-phenylpyridine.

- [0095] Bis(2,4-diphenylpyridine-C²,N¹)(acetylacetonato)iridium (III) (Ex. Comp. No. 522).
- [0096] Tris(2,4-diphenylpyridine-C²,N¹)iridium (III) (Ex. Comp. No. 527).

Example 16 (Synthesis of Ex. Comp. Nos. 523 and 528)

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[0097] It is easy to synthesize the following compounds in the same manner as in Example 11 except that 2-(biphenyl-3-yl)pyridine is synthesized from 3-biphenylboronic acid (made by Lancaster Co.) and 2-bromopyridine (made by Tokyo Kasei Kogyo K.K.) and is used instead of 2-(benzo[b]thienyl)-5-phenylpyridine.

- [0098] Bis[2-(biphenyl-3-yl)pyridine-C⁴N¹)(acetyl-acetonato)iridium (III) (Ex. Comp. No. 523).
- ¹⁵ **[0099]** Tris[2-(biphenyl-2-yl)pyridine-C⁴,N¹)iridium (III) (Ex. Comp. No. 528).

Example 17 (Synthesis of Ex. Comp. Nos. 524 and 529)

- [0100] It is easy to synthesize the following compounds in the same manner as in Example 11 except that 2-(5bromothiophene-2-yl)pyridine is synthesized from 2-bromopyridine (made by Tokyo Kasei Kogyo K.K.) and 5-bromothiophene-2-boronic acid (made by Aldrich Co.) and was reacted with phenylboronic acid (made by Tokyo Kasei Kogyo K.K.) to obtain 2-(5-phenylthiophene-2-yl)pyridine, which is used instead of 2-(benzo[b]thienyl)-5-phenylpyridine.
 - [0101] Bis[2-(5-phenylthiophene-2-yl)pyridine-C³,N¹)(acetylacetonato)iridium (III) (Ex. Comp. No. 524).
- 25 [0103] As described above, a metal coordination compound according to the present invention has an aromatic substituent. The electroluminescence device (luminescence device) of the present invention using, as a luminescent center material, this metal coordination compound is an excellent device which not only allows high-efficiency luminescence but also retains a high luminance for a long period and shows little deterioration by current passage. Further, the display apparatus using the electroluminescence device of the present invention exhibits excellent display performances.

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Claims

A metal coordination compound selected from the group of compounds represented by the following formulae (1) to (17):



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formula (6):





formula (14):



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15 2. An electroluminescence device, comprising: a pair of electrodes disposed on a substrate, and a luminescence unit comprising at least one species of an organic compound disposed between the pair of electrodes, wherein said at least one species of an organic compound is a metal coordination compound according to claim 1.



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3. A picture display apparatus, comprising an electroluminescence device according to claim 2, and means for supplying electric signals to the electroluminescence device.

5 Patentansprüche

1. Metallkoordinationsverbindung, ausgewählt aus der durch die folgenden Formeln (1) bis (17) dargestellten Verbindungen:













 Elektrolumineszenzvorrichtung, umfassend: ein auf einem Substrat angeordnetes Elektrodenpaar und eine Lumineszenzeinheit, die zumindest eine Spezies einer zwischen dem Elektrodenpaar angeordneten organischen Verbindung umfasst, wobei die zumindest eine Spezies einer organischen Verbindung eine Metallkoordinationsverbindung nach Anspruch 1 ist.

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3. Bildanzeigeapparat, der eine Elektrolumineszenzvorrichtung nach Anspruch 2 und Einrichtungen zum Zuführen

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elektrischer Signale zu der Elektrolumineszenzvorrichtung umfasst.

Revendications

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1. Composé de coordination métallique choisi dans le groupe de composés représentés par les formules (1) à (17) suivantes :

10 15	fo	rmule	(1)	:	
20	fo	rmule	(2)	:	
25	· · ·				"{}] ₃
30	fo	rmule	(3)	:	
35	fo	rmule	(4)	:	
40			x - /	-	

formule (5) :

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formule (10) :





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- formule (11) :
 - formule (12) :

- formule (13) :
- formule (14) :

















 Dispositif électroluminescent, comprenant : une paire d'électrodes disposées sur un substrat, et une unité lumines cente comprenant au moins un type d'un composé organique disposé entre les deux électrodes, dans lequel ledit au moins un type de composé organique est un composé de coordination métallique suivant la revendication 1.

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3. Appareil d'affichage d'image, comprenant un dispositif électroluminescent suivant la revendication 2, et un moyen pour fournir des signaux électriques au dispositif électroluminescent.

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FIG. 1A



FIG. 1B





FIG. 2



FIG. 3C

REFERENCES CITED IN THE DESCRIPTION

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patsnap

专利名称(译)	金属配位化合物,发光装置和显示∛	麦置	
公开(公告)号	EP1239526B1	公开(公告)日	2008-12-17
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代理机构(译)	TBK专利		
优先权	2001064204 2001-03-08 JP 2002042440 2002-02-20 JP		
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外部链接	Espacenet		

摘要(译)

提供了一种具有含有特定金属配位化合物的层的电致发光器件。金属配位化合物由下式(1)表示:MLmL'n(1),其中M是 Ir,Pt,Rh或Pd的金属原子;L和L'是相互不同的二齿配体;m为1,2或3,n为0,1或2,条件是m+n为2或3;部分结构MLm由下 面所示的式(2)表示,部分结构ML'n由下面所示的式(3)或(4)表示:式(1)的金属配位化合物的特征在于至少具有 CyN1,CyN2,CyC1和CyC2中至少一种的一个芳族取代基。具有芳族取代基的金属配位化合物可有效地提供高效发光,长期高亮 度和通过电流通过的较少劣化。

